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# 2SA673A(K)

Silicon PNP Epitaxial

# HITACHI

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## Application

- Low frequency amplifier
- Medium speed switching

## Outline

TO-92 (1)



1. Emitter
2. Collector
3. Base

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## 2SA673A(K)

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### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	-50	V
Collector to emitter voltage	$V_{CEO}$	-50	V
Emitter to base voltage	$V_{EBO}$	-4	V
Collector current	$I_C$	-0.5	A
Collector power dissipation	$P_C$	0.4	W
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

**Electrical Characteristics** (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-50	—	—	V	$I_C = -10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-50	—	—	V	$I_C = -1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-4	—	—	V	$I_E = -10 \mu A, I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	-0.5	$\mu A$	$V_{CB} = -20 \text{ V}, I_E = 0$
Emitter cutoff current	$I_{EBO}$	—	—	-0.5	$\mu A$	$V_{EB} = -3 \text{ V}, I_C = 0$
Base to emitter voltage	$V_{BE}$	—	-0.64	—	V	$V_{EB} = -3 \text{ V}, I_C = -10 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	-0.2	-0.6	V	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}^{*2}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	-0.87	—	V	$I_C = -150 \text{ mA}, I_B = -15 \text{ mA}^{*2}$
DC current transfer ratio	$h_{FE}^{*1}$	60	—	320		$V_{CE} = -3 \text{ V}, I_C = -10 \text{ mA}$
	$h_{FE}$	10	—	—		$V_{CE} = -3 \text{ V}, I_C = -500 \text{ mA}^{*2}$
Gain bandwidth product	$f_T$	—	120	—	MHz	$V_{CE} = -3 \text{ V}, I_C = -10 \text{ mA}$
Turn on time	$t_{on}$	—	0.3	—	$\mu s$	$V_{CC} = -10.3 \text{ V}$
Turn off time	$t_{off}$	—	0.6	—	$\mu s$	$I_C = 10 \text{ mA}, I_{B1} = -10 \text{ mA}, I_{B2} = -10 \text{ mA}$
Storage time	$t_{stg}$	—	0.4	—	$\mu s$	$V_{CC} = -5 \text{ V}, I_C = I_{B1} = I_{B2} = -20 \text{ mA}$

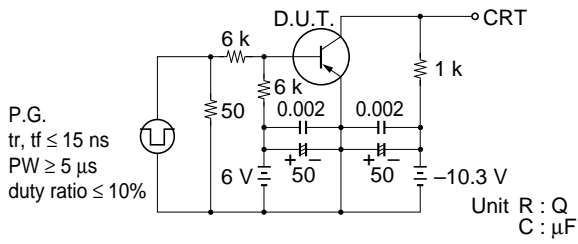
Notes: 1. The 2SA673A(K) is grouped by  $h_{FE}$  as follows.

2. Pulse test

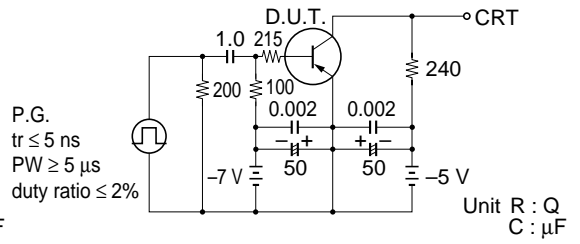
B	C	D
60 to 120	100 to 200	160 to 320

See 2SA673A except for the above – mentioned characteristic curves.

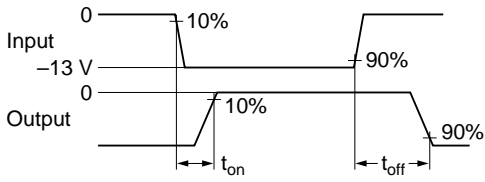
Switching Time Test Circuit  
 $t_{on}$ ,  $t_{off}$  Test Circuit



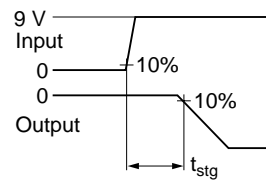
Switching Time Test Circuit  
 $t_{stg}$  Test Circuit

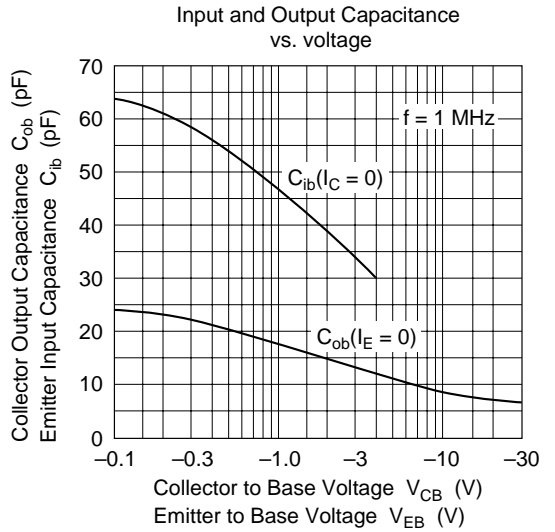
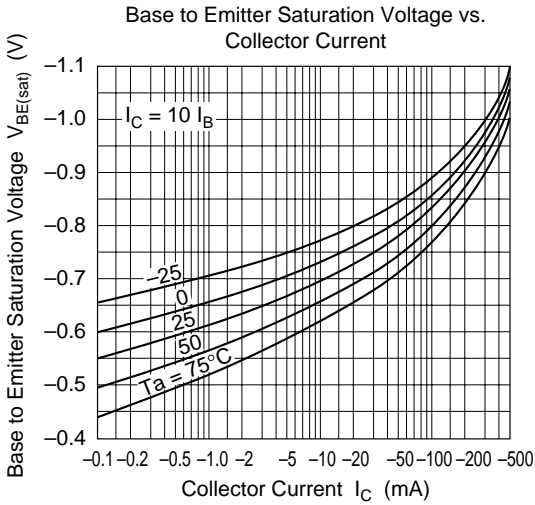
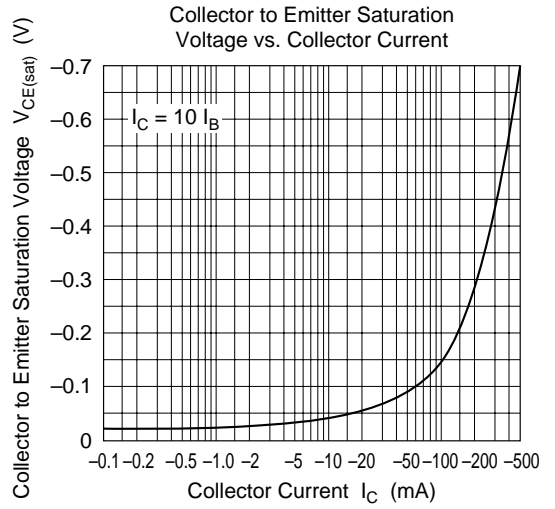
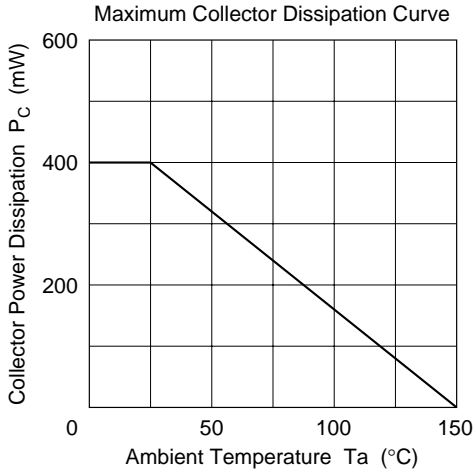


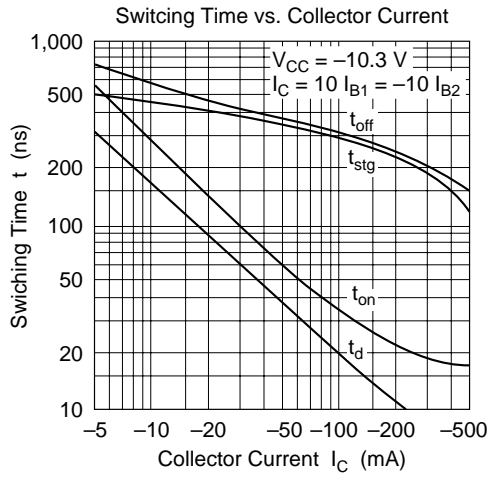
Response Waveform

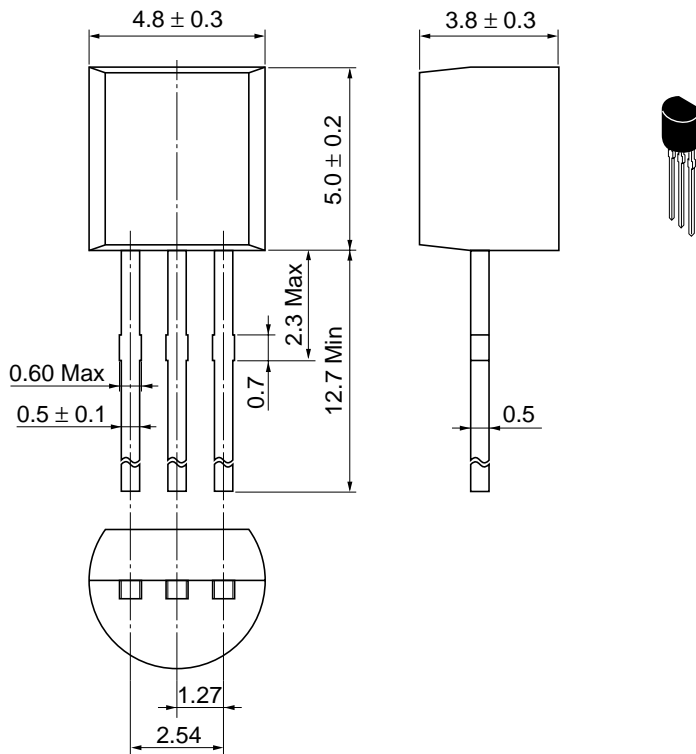


Response Waveform









Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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# HITACHI

## Hitachi, Ltd.

Semiconductor & Integrated Circuits.  
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan  
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL      North America      : <http://semiconductor.hitachi.com/>  
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## For further information write to:

Hitachi Semiconductor  
(America) Inc.  
179 East Tasman Drive,  
San Jose, CA 95134  
Tel: <1> (408) 433-1990  
Fax: <1>(408) 433-0223

Hitachi Europe GmbH  
Electronic components Group  
Dornacher Straße 3  
D-85622 Feldkirchen, Munich  
Germany  
Tel: <49> (89) 9 9180-0  
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.  
Electronic Components Group.  
Whitebrook Park  
Lower Cookham Road  
Maidenhead  
Berkshire SL6 8YA, United Kingdom  
Tel: <44> (1628) 585000  
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.  
16 Collyer Quay #20-00  
Hitachi Tower  
Singapore 049318  
Tel: 535-2100  
Fax: 535-1533

Hitachi Asia Ltd.  
Taipei Branch Office  
3F, Hung Kuo Building, No.167,  
Tun-Hwa North Road, Taipei (105)  
Tel: <886> (2) 2718-3666  
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.  
Group III (Electronic Components)  
7/F., North Tower, World Finance Centre,  
Harbour City, Canton Road, Tsim Sha Tsui,  
Kowloon, Hong Kong  
Tel: <852> (2) 735 9218  
Fax: <852> (2) 730 0281  
Telex: 40815 HITEC HX

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